

Spectroscopic Surface Methods

Electron Spectroscopies

XPS: X-ray Photoelectron Spectroscopy AES: Auger Electron Spectroscopy EELS: Electron Energy Loss Spectroscopy

Ion Spectroscopies

SIMS: Secondary Ion Mass Spectrometry LMMS: Laser Microprobe Mass Spectrometry ISS: Ion Scattering and Rutherford Backscattering Spectroscopy

• General Information on Electron Spectroscopy:

- Electron spectroscopy can be used for the identification of all of the elements in the periodic table except for helium and hydrogen.
- The method also permits the determination of the oxidation state of an element and the type of species to which it is bonded.
- This technique also provides useful information about the electronic structure of molecules.

- The kinetic energy of the emitted electron E_k is measured in an electron spectrometer. The binding energy of the electron E_b can be calculated

$$\Xi_b = hv - E_k - w$$

where, w is the work function of the spectrometer, a factor that corrects for the electrostatic environment in which the electron is formed and measured.

X-ray Photoelectron Spectroscopy (XPS)

- X-ray Photoelectron Spectroscopy (XPS), also known as Electron Spectroscopy for Chemical Analysis (ESCA) is a widely used technique to investigate the chemical composition of surfaces.
- X-ray Photoelectron spectroscopy, based on the photoelectric effect was developed in the mid-1960's by Kai Siegbahn and his research group at the University of Uppsala, Sweden.
- The advent of commercial manufacturing of surface analysis equipment in the early 1970s enabled the placement of equipment in laboratories throughout the world.
- In 1981, Siegbahn was awarded the Nobel Prize for Physics for his work with XPS.

X-ray Photoelectron Spectroscopy (XPS)



are emitted from this entire area

X-Ray Photoemission spectroscopy (XPS) uses X-ray radiation to probe the binding energy of electrons of the material under study.



- The incoming light with a fixed photon energy excites electrons from their bound states into free electrons with a kinetic energy that is smaller for formerly stronger bound electrons.
- With an energy analyzer, electrons of specific kinetic energy can be selected and counted by the detector. Thus the signal is the number of counted electrons over kinetic energy.

- X-Ray Photoelectron Spectroscopy (XPS), not only provided information about the atomic composition of the sample, but also information about the structure and oxidation state of the compounds being examined
- An important advantage of XPS is its ability to obtain information on chemical states from the variations in binding energies, or chemical shifts, of the photoelectron lines.
- The relative concentrations of elements can be determined from the photoelectron intensities.





FIGURE 21-3 Schematic representation of the ESCA process.

 $E_{\rm k} \approx h - E_{\rm b}$ • The incident beam consists of monoenergetic X-rays. The emitted beam is made up of electrons.

> • XPS spectral lines are identified by the shell from which the electron was ejected (1s, 2s, 2p, etc.)

• The ejected photoelectron has kinetic energy:

*KE=hv-BE-*W

W: work function of the spectrometer

• Following this process, the atom will release energy by the emission of an Auger Electron.

• The XPS instrument measures the kinetic energy of all collected electrons. The electron signal includes contributions from both photoelectron and Auger electron lines.



Auger Relation of Core Hole



FIGURE 21-7 Schematic representation of the source of

- (a) Auger electron emission and
- *(b)* X-ray fluorescence that competes with Auger emission.

Auger Photoelectron Spectroscopy

- Auger electron spectroscopy (AES) is the second type of electron spectroscopy.
- Auger spectra are most commonly excited by a beam of electrons, although X-rays are also used.
- Photoelectron line energies: **Dependent** on photon energy.
- Auger electron line energies: Not Dependent on photon energy.
- If XPS spectra were presented on a kinetic energy scale, one would need to know the X-ray source energy used to collect the data in order to compare the chemical states in the sample with data collected using another source.



UV-Photoelectron Spectroscopy

- The third type of electron spectroscopy is ultraviolet photoelectron spectroscopy (UPS).
- In this method, a monochromatic beam of ultraviolet radiation causes the ejection of electrons form the analyte.
- This method is not as common as the first two methods.



Instrumentation for XPS

Surface analysis by XPS requires irradiating a solid in an Ultra-high Vacuum (UHV) chamber with monoenergetic soft X-rays and analyzing the energies of the emitted electrons.

Why UHV for Surface Analysis?



Pressure

- Remove adsorbed gases from the sample.
- Eliminate adsorption of contaminants on the sample.
- Prevent arcing and high voltage breakdown.
- Increase the mean free path for electrons, ions and photons.

X-ray Photoelectron Spectrometer



X-ray Photoelectron Spectrometer

Hemispherical Energy Analyzer **Outer Sphere** Magnetic Shield Analyzer Control **Inner Sphere** Electron Lenses for Energy Multi-Channel Plate **Optics** Adjustment Electron Multiplier (Retardation) **Resistive Anode** X-ray Encoder Source **Position Computer** Lenses for Analysis Position Address Area Definition Converter **Position Sensitive** Sample Detector (PSD) 54.7

Computer System





• When we focus on the kinetic energy connected with electrons from a certain state of an element the chemical environment of the element is reflected in small shift of the binding energy of that state.



A hydrogen (white), a carbon (black), and an oxygen (red) atom.



A terephtalic acid molecule featuring a phenyl (C6H4) and two carboxyl (COOH) units.



Deprotonated variant of the same molecule having two carboxylate (COO-) units.

• For example carbon atoms have 1s electron with a binding energy of typically 285 eV.

• If the carbon atoms are connected to other atoms like in phenyl (Ph), carbon monoxide (CO), carboxylate (COO-) or carboxyl (COOH) groups, each group exhibits a characteristic binding energy.

• By analyzing peak positions and intensities under different experimental situations one determines the states of the sample. Applications of X-ray Photoelectron Spectroscopy (XPS)



FIGURE 21-2 X-ray photoelectron spectrum of tetrapropylammoniumdifluoridethiophosphate. The peaks are labeled according to the element and orbital from which the emitted electrons originate.

Ch21 Surface Characterization by Spectroscopy and Microscopy

XPS Analysis of Pigment from Mummy Artwork



Analysis of Carbon Fiber- Polymer Composite Material by XPS

N(E)/E





Woven carbon fiber composite XPS analysis identifies the functional groups present on composite surface. Chemical nature of fiber-polymer interface will influence its properties.



Analysis of Materials for Solar Energy Collection by XPS Depth Profiling-

The amorphous-SiC/SnO₂ Interface

Photo-voltaic Collector



Solar Energy



The profile indicates a reduction of the SnO_2 occurred at the interface during deposition. Such a reduction would effect the collector's efficiency. SnO_2



Data courtesy A. Nurrudin and J. Abelson, University of Illinois



Angle-resolved XPS



Angle-resolved XPS Analysis of Self-Assembling Monolayers



Data courtesy L. Ge, R. Haasch and A. Gewirth, University of Illinois

Electron Energy Loss Spectroscopy, (EELS) for chemical and compositional analysis

What is EELS

Electron energy loss spectroscopy (EELS) is a family of techniques that measure the change in kinetic energy of electrons after they interact with a specimen.

In EELS the energy distribution of electrons that pass through a thin sample is used to analyze the content of the sample and create images with unique contrast effects.

This technique is used to determine the atomic structure and chemical properties of a specimen, including: the type and quantity of atoms present, chemical state of atoms and the collective interactions of atoms with their neighbors.

Electron Energy Loss Spectroscopy

As electrons pass through a specimen, they interact with atoms of the solid.

Many of the electrons pass through the thin sample without losing energy.

A fraction will undergo inelastic scattering and lose energy as they interact with the specimen.

This leaves the sample in an excited state. The material can de-excite by giving up energy typically in the form of visible photons, x-rays or Auger electrons.



Atom-scale view of electron energy loss

As the incident electron interacts with the sample, it changes both its energy and momentum.

➤ You can detect this scattered incident electron in the spectrometer as it gives rise to the electron energy loss signal.

The sample electron (or collective excitation) carries away this additional energy and momentum

EELS-Instrumentation



EELS instrumentation is typically incorporated into a transmission electron microscope (TEM) or a scanning TEM (STEM). These microscope types use high energy electrons (60 - 300 kV)typically) to interrogate the sample. As the name implies, the electrons must "transmit" through the sample and thus requires an electron transparent sample. The electrons can interact either elastically (no energy exchange) or inelastically with the sample, and it is these interactions that EELS exploits to extract information about the sample.

Specimen information provided by EELS signal



A typical energy loss spectrum. The spectrum has many prominent features and is typically separated into three regions: electrons that have not lost energy (zero-loss peak), electrons that have interacted with the weakly bound electrons in the sample (low-loss distribution), and the electrons that have interacted with the tightly bound core electrons of the atoms (the ionization edges or core-loss region).

➤ a wealth of information from the sample, including:

- Specimen thickness Zero-loss peak (ZLP) and total spectrum intensity
- Valence/conduction electron density Plasmon peaks
- > Optical response (complex dielectric function) Low-loss distribution
- Band structure and interband transitions Near zero-loss features
- Elemental composition Core-loss edges
- Bonding and oxidation state (density of unoccupied states) Near edge fine structure (ELNES)
- > Distribution of near neighboring atoms (radial distribution function RDF)
- Extended energy loss fine structure (ExELFS)

EELS limitations

➤ The main limitation of the EELS technique is the effect of sample thickness. As the sample thickness increases, the strong interaction of primary electrons within the sample results in the electrons undergoing multiple energy loss events. This tends to reduce the signal-to-background ratio of the EELS edges, reducing the visibility of the edges. However, since the spatial resolution of transmission electron microscope techniques is also reduced as the thickness increases, this loss of the edge visibility is not always the largest impediment to quality data.